

Q

## High Speed CMOS 1-of-8 Decoders

QS54/74FCT138T  
QS54/74FCT238T

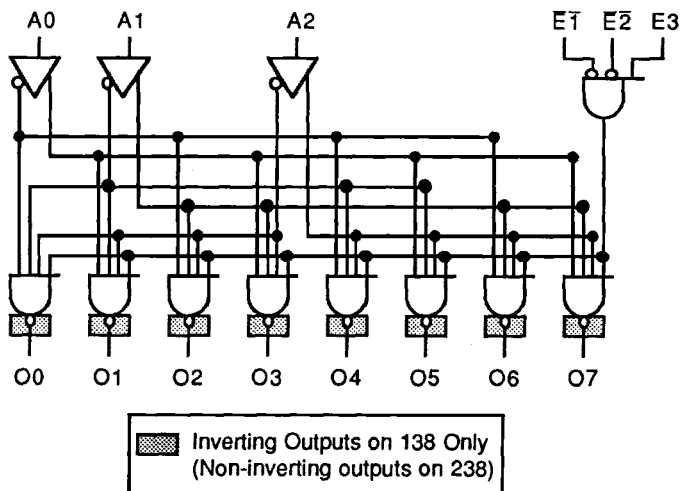
### FEATURES/BENEFITS

- QSFCT138A faster than 74F
- $I_{OL}=48$  mA COM, 32 mA MIL
- TTL-compatible input and output levels
- Mil product compliant with MIL-STD 883, Class B
- QSFCT238T has positive active outputs
- CMOS power levels < 7.5 mW static
- Available in DIP, ZIP, SOIC, QSOP, LCC
- JEDEC standard pinouts

### DESCRIPTION

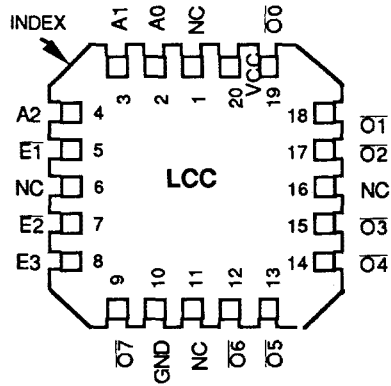
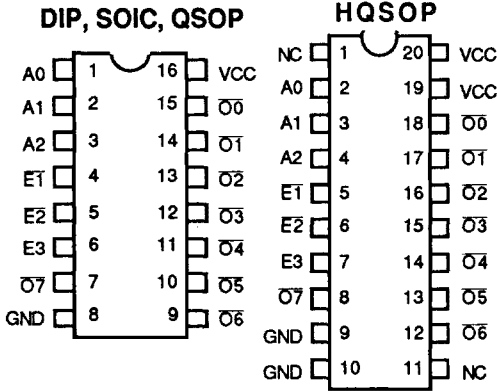
The QSFCT138T and QSFCT238T are high speed CMOS TTL-compatible high speed binary decoders. The QSFCT138T has negative active outputs, and the QSFCT238T has positive active outputs. The high output current  $I_{OL}$  and  $I_{OH}$  drive high capacitance loads. All inputs have clamp diodes for undershoot noise suppression. All outputs have ground bounce suppression (see QSI Application Note AN-001), and outputs will not load an active bus when  $V_{CC}$  is removed from the device.

### FUNCTIONAL BLOCK DIAGRAM

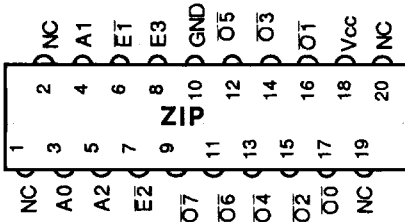


4

**PIN CONFIGURATIONS**



**ALL PINS TOP VIEW**



Name	I/O	Description
Ai	I	Select Inputs
Oi	O	Decode Outputs
Ei	I	Enable

Output State	Output Level	
	138	238
0	H	L
1	L	H

Enable			Select			Output							Function	
E1	E2	E3	A2	A1	A0	O7	O6	O5	O4	O3	O2	O1		O0
H	X	X	X	X	X	0	0	0	0	0	0	0	0	Disable
X	H	X	X	X	X	0	0	0	0	0	0	0	0	Disable
X	X	L	X	X	X	0	0	0	0	0	0	0	0	Disable
L	L	H	L	L	L	0	0	0	0	0	0	0	1	A2-0 = 0
L	L	H	L	L	H	0	0	0	0	0	0	1	0	A2-0 = 1
L	L	H	L	H	L	0	0	0	0	0	1	0	0	A2-0 = 2
L	L	H	L	H	H	0	0	0	0	1	0	0	0	A2-0 = 3
L	L	H	H	L	L	0	0	0	1	0	0	0	0	A2-0 = 4
L	L	H	H	L	H	0	0	1	0	0	0	0	0	A2-0 = 5
L	L	H	H	H	L	0	1	0	0	0	0	0	0	A2-0 = 6
L	L	H	H	H	H	1	0	0	0	0	0	0	0	A2-0 = 7

**ABSOLUTE MAXIMUM RATINGS**

Supply Voltage to Ground.....	-0.5V to +7.0V
DC Output Voltage $V_O$ .....	-0.5V to 7.0V
DC Input Voltage $V_I$ .....	-0.5V to 7.0V
AC Input Voltage (for a pulse width $\leq 20$ ns).....	-3.0V
DC Input Diode Current with $V_I < 0$ .....	-20 mA
DC Output Diode Current with $V_O < 0$ .....	-50 mA
DC Output Current Max. sink current/pin.....	120 mA
Maximum Power Dissipation.....	0.5 watts
$T_{STG}$ Storage Temperature.....	-65° to +165°C

**CAPACITANCE**

$T_A = 25^\circ\text{C}$ ,  $f = 1\text{ MHz}$ ,  $V_{in} = 0\text{V}$ ,  $V_{out} = 0\text{V}$

Pins	SOIC	QSOP	PDIP,LCC	ZIP	Unit
1-3	4	4	5	7	pF
7,9-12	6	6	7	9	pF
4-6,13-15	8	8	9	10	pF

Note: Capacitance is characterized but not tested



**DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE**

Commercial  $T_A = 0^\circ\text{C}$  to  $70^\circ\text{C}$ ,  $V_{CC} = 5.0\text{V} \pm 5\%$       Military  $T_A = -55^\circ\text{C}$  to  $125^\circ\text{C}$ ,  $V_{CC} = 5.0\text{V} \pm 10\%$

Symbol	Parameter	Test Conditions		Min	Typ (1)	Max	Unit
$V_{ih}$	Input High Voltage	Logic HIGH for All Inputs		2.0	-	-	Volts
$V_{il}$	Input LOW Voltage	Logic LOW for All Inputs		-	-	0.8	
$\Delta V_t$	Input Hysteresis	$V_{th} - V_{tl}$ for All Inputs		-	0.2	-	
$ I_{ih} $ $ I_{il} $	Input Current Input HIGH or LOW	$V_{CC} = \text{MAX}$	$0 \leq V_{in} < V_{CC}$	-	-	5	$\mu\text{A}$
$ I_{oz} $	Off State Output Current (Hi-Z)	$V_{CC} = \text{MAX}$ , $0 \leq V_{in} \leq V_{CC}$		-	-	5	
$I_{os}$	Short Circuit Current	$V_{CC} = \text{MAX}$ , $V_o = \text{GND}$ (2,3)		-60	-	-225	mA
$V_{ic}$	Input Clamp Voltage	$V_{CC} = \text{MIN}$ , $I_{in} = 18\text{ mA}$ (3)		-	-0.7	-1.2	Volts
$V_{oh}$	Output HIGH Voltage	$V_{CC} = \text{MIN}$	$I_{oh} = 12\text{ mA}$ (MIL)	2.4	-	-	Volts
			$I_{oh} = 15\text{ mA}$ (COM)	2.4	-	-	
$V_{ol}$	Output LOW Voltage	$V_{CC} = \text{MIN}$	$I_{ol} = 32\text{ mA}$ (MIL)	-	-	0.50	
			$I_{ol} = 48\text{ mA}$ (COM)	-	-	0.50	

**Notes:**

1. Typical values indicate  $V_{CC} = 5.0\text{V}$  and  $T_A = 25^\circ\text{C}$ .
2. Not more than one output should be shorted and the duration is  $\leq 1$  second.
3. These parameters are guaranteed by design but not tested.

**POWER SUPPLY CHARACTERISTICS**

Symbol	Parameter	Test Conditions (1)	Min	Max	Unit
I <sub>cc</sub>	Quiescent Power Supply Current	V <sub>cc</sub> = MAX, freq = 0 0V ≤ V <sub>in</sub> ≤ 0.2V or V <sub>cc</sub> - 0.2V ≤ V <sub>in</sub> ≤ V <sub>cc</sub>	-	1.5	mA
ΔI <sub>cc</sub>	Supply Current per Input @ TTL HIGH	V <sub>cc</sub> = MAX, V <sub>in</sub> = 3.4 V, freq = 0 (2)	-	2.0	
Q <sub>ccd</sub>	Supply Current per input per MHz	V <sub>cc</sub> = MAX, Outputs open and enabled One bit toggling @ 50% duty cycle Other inputs at GND or V <sub>cc</sub> (3,4)	-	0.25	mA/ MHz

1. For conditions shown as MIN or MAX use the appropriate values specified under DC specifications.
2. Per TTL driven input (V<sub>i</sub>=3.4V)
3. For flipflops Q<sub>ccd</sub> is measured by switching one of the data input pins so that the output changes every clock cycle. This is a measurement of device power consumption only and does not include power to drive load capacitance or tester capacitance. This parameter is guaranteed by design but not tested.
4. I<sub>c</sub> can be computed using the above parameters as explained in the Technical Overview section.

**SWITCHING CHARACTERISTICS OVER OPERATING RANGE**

Commercial TA = 0° C to 70°C, V<sub>cc</sub> = 5.0V±5% Military TA = -55°C to 125° C, V<sub>cc</sub> = 5.0V±10%  
 Cload = 50 pF, Rload = 500Ω unless otherwise noted

Symbol	Description	Notes (1)	138, 238		138A 238A		138C 238C		138D 238D		Unit  ns
			Min	Max	Min	Max	Min	Max	Min	Max	
t <sub>PHL</sub> t <sub>PLH</sub>	Propagation Delay A <sub>i</sub> to O <sub>i</sub>	COM	1.5	9	1.5	5.8	1.5	5.0	1.0	4.0	
		MIL	1.5	12	1.5	7.8	1.5	7.0			
t <sub>PHLE</sub> t <sub>PLHE</sub>	Propagation Delay E <sub>i</sub> to O <sub>i</sub>	COM	1.5	8	1.5	5.9	1.5	5.0	1.0	4.0	
		MIL	1.5	12	1.5	8.0	1.5	7.0			

**Notes:**

- 1) Minimums guaranteed but not tested. See Test Circuit and Waveforms.